

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	110774	BP or (boron near phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:30
L2	122	group-III near3 nitride near semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:31
L3	25	I1 and I2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:31
L4	906	I1 and (GaN or (gallium near nitride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:32
L5	4842	(257/16 or 257/22 or 257/99 or 257/103 or 257/189 or 257/190).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:34
L6	41	I1 and I5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:35
L7	2271	(438/22 or 438/46 or 438/47).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:36
L8	26	I1 and I7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/08 10:37